Electronic Supplementary Information

A comparative investigation of chemical reduction of graphene oxide for electrical engineering applications

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Section A. Materials and characterization

Experimental details

Materials: L-ascorbic acid (AA), sodium borohydride (NaBH₄), hydrazine monohydrate (N₂H₄), sodium hydrosulfite (Na₂S₂O₄), 25 wt% ammonia solution (NH₃), potassium carbonate (K₂CO₃), ethanol. All of the reductors were bought from Sigma-Aldrich and used directly without further purification. Gaphene Oxide (GO) water dispersion with concentration 1 wt% was acquired from Graphenea, Separators Whatman® glass microfiber filters, binder poly(tetrafluoroethylene) and 1-methyl-2-pyrrolidinone were purchased from Sigma Aldrich. Conductive Carbon Black Super P (H30253) was acquired from Alfa Aesar and carbon AvCarb P75 substrate was gained from FuelCellStore.

GO films. GO water solution (0.4 mg/mL) was spray coated onto polyethylene terephthalate (PET) substrates at 90°C ($2.5 \times 1.2 \text{ cm}^2$).

General reduction procedure: An aqueous dispersion of 30 mL of GO 10 mg/mL was diluted in 270 mL of Milli Q water and sonicated for 20 minutes in an ultrasonic bath cleaner (140 w). Subsequently, the reducing reagent was added and the pH adjusted to 9-10. The reaction mixture was stirred for a certain amount of time (see Table S1) at 95 °C. The chemicallyreduced GO (CrGO) was collected by filtration and washed thoroughly with deionized water and ethanol. The black precipitate was then freeze-dried for 72 h under vacuum.

Reducing agent	Concentration (g/L)	pH adjusting reagent	Reaction time (h)	Reaction temperature (°C)
NaBH ₄	8	5 wt% K ₂ CO ₃	2	95
$NaBH_4$	8	$5 \text{ wt\% } \text{K}_2\text{CO}_3$	12	95
Ascorbic Acid	8	25 wt\% NH_3	2	95
Ascorbic Acid	8	25 wt\% NH_3	12	95
N_2H_4	10	-	2	95
N_2H_4	10	-	12	95
$Na_2S_2O_4$	7.5	25 wt% NH ₃	2	95
$Na_2S_2O_4$	7.5	25 wt% NH ₃	12	95

Table S1. Synthetic conditions studied for the preparation of CrGO.

Reduction of GO films: GO films were immersed in 30 mL aqueous solution of the reducing agent at the desired concentration (dilution 1:10 of the amount indicated in Table S1) for 2 hours.

Methods: Structural data were obtained by X-Ray diffraction (XRD) with the use of Bruker AXS D8 Advance diffractometer in Bragg-Brentano geometry with CuK_{α 1} radiation ($\lambda = 1.5406$ Å). X-ray Photoelectron Spectroscopy (XPS) analyses were performed with a Thermo Scientific K_a X-ray Photoelectron Spectrometer system equipped with an Al K_a X-Ray source (photon energy $E_{ph} = 1486.6$ eV, beam spot size ~100 µm. For the **nuclear magnetic resonance** (NMR) spectroscopy ¹H and ¹³C spectra were recorded on a Bruker Avance III HD spectrometer coupled to an 11.7 T wide bore superconducting magnet operating at 500 MHz ¹H Larmor frequency and 125.76 MHz ¹³C Larmor frequency. All spectra were recorded at 298K stabilized temperature using the magic-angle spinning technique for high-resolution NMR spectroscopy in solid-state using 4mm zirconia rotors. The spinning frequency was equal to 12 kHz for ¹H and ¹³C nuclei. A speed synchronized spin-echo was included inside the experimental pulse sequences for the ¹H and ¹³C spectra, recoded with direct polarization to get undistorted line shapes and filter out background probe signals. The echo time was kept identical for all ¹H and ¹³C spectra and equal one rotation period. The total echo time was 83 µs, the recycle delay was 5 s, and the number of scans was 512 for proton spectra. Due to the very high conductivity of studied samples, no cross-polarization experiment was possible, owning to non-effective energy transfer. Therefore, the ¹³C spectra were recorded using the direct polarization method with recycle delay equal to 10 s and 8192 scans, leading to almost 23 hours of data accumulation per spectrum. Elemental analysis (EA) was performed on an Elementar Analyser Vario EL III. Pore-size distribution and specific surface area of (Cr)GO samples were investigated by the nitrogen adsorption-desorption isotherm (Autosorb iQ, Quantachrome) using Barrett-Joyner-Halenda (BJH) and Bruanauer-Emmett-Teller (BET) techniques, respectively. Scanning electron microscopy (SEM) was performed on an FEI Quanta 250 FEG Scanning Electron Microscope operating at an accelerating voltage of 5 keV incident beam energy. Raman spectra were performed using a Renishaw InVia Reflex system. The spectrograph used a high-resolution grating (2400 grooves cm⁻¹) with additional bandpass filter optics, a confocal microscope, and a 2D-CCD camera. The excitation was carried out using a 532 nm laser excitation beam, with a 100× objective, 0.2 mW maximum power and 1 s acquisition time. Thermogravimetric analysis (TGA) was carried out in the temperature range 30–1000 °C operating under ambient conditions, with a ramp rate of 10 °C min⁻¹ on a Mettler Toledo TGA/SDTA851e system. Fourier transform infrared (FTIR) spectra were recorded within the mid-IR range (500–4000 cm⁻¹) using a PerkinElmer spectrometer (spectrum two) equipped with ATR Diamond.

Four-Point Probe measurements. Electrical conductivity measurements were conducted on pelletized samples: 50 mg of GO or CrGO were pressed under 10 tons with a Specac press machine. Films electrical resistivity were measured with Jandel, Model RM3000, limit of detection 10⁷ Wsq⁻¹. The resistivity (r) was obtained

$$\rho = R_s \cdot l \tag{1}$$

Where Rs is the sheet resistance and l is thickness of the film.

Calculation of the average defect distance (L_D):

$$L_D^2(nm^2) = (1.8 \pm 0.5) \times 10^{-9} \lambda_L^4 \left(\frac{I_D}{I_G}\right)^{-1}$$
(2)

Where, λ_L is the laser wavelength (nm)

Calculation of defect density (n_D):

$$n_D(cm^{-2}) = \frac{(1.8 \pm 0.5) \times 10^{22}}{\lambda_L^4} \left(\frac{I_D}{I_G}\right)$$
(3)

Fabrication of supercapacitors. The electrochemical performance of the chemically reduced graphene oxide was measured in a two-electrode symmetric supercapacitor system. Two electrodes were assembled in CR2032 stainless steel coin-type cells with a Whatman® glass microfiber filters as a separator and $1 \text{ M H}_2\text{SO}_4$ aqueous solution as electrolyte.

The working electrodes were prepared by mixing of given rGO sample (80% wt%, 8 mg), carbon black (10wt%, 1 mg) and PTFE (10wt%, 1 mg) with 1 ml of NMP, sonicated for 20 mins and subsequently droplet deposited on carbon substrate placed on hot plate (80° C) to quickly evaporate the solvent achieving homogenously covered electrode. The electrodes were

additionally dried under vacuum at 80° C (24h). The mass loading of the (chemically-reduced) graphene oxide was ~2-3 mg in each electrode.

The devices were electrically characterized by cyclic voltammetry (CV), galvanostatic charge/discharge (GCD) and electrochemical impedance spectroscopy (EIS) employing a EC-LAB VMP3 (BioLogic Science Instruments). CV was performed in the potential window from 0 to 1 V at scan rates ranging from 2 mV/s to 1000 mV/s. GCD curves were recorded in the same potential window at different current densities (1-10 A/g). The frequency range for the impedance spectra was from 100 kHz to 1 mHz with a sine-wave voltage signal amplitude of 10 mV (root-mean-square, RMS).

Calculation of the specific capacitances, energy densities and power densities. From charge-discharge measurements, the specific capacitances (Cp), energy densities (E) and power densities (P) of (chemically reduced) graphene oxide were obtained from the acquired data using following equations¹:

$$Cp = \frac{2 \cdot I \cdot \Delta t}{m \cdot \Delta V} \tag{4}$$

$$E = \frac{1}{2} \cdot Cp \cdot \Delta V^2 \tag{5}$$

$$P = \frac{E}{\Delta t} \tag{6}$$

where I is the discharge current (A), Δt is the discharge time (s), m is the weight of the active material in an individual electrode (g), and ΔV is the discharge voltage (V) excluding the internal iR drop during the discharge process.

Calculation of ionic conductivity (σ)

$$\sigma = \frac{l}{R_i \cdot A} \tag{7}$$

Being 1 the film thickness (100 μ m), A the film area (1.27 cm²) and Ri is the ionic resistance.

Toxicological analysis

Evaluation of skin irritation:

SkinEthicTM Reconstructed Human Epidermis (RhE, provided by EpiSkin; Lyon, France), was used for evaluating skin irritation potential of rGOs, following the OECD Test Guideline (TG) No. 439. According to the TG, before being used for the experiments, RhE tissues were checked for quality control criteria (mean optical density, O.D., of 3 negative controls = 1.15 ± 0.05 ; mean viability of 3 positive controls, 5% SDS = 1.3 ± 0.1 %; exposure time inducing 50 % viability using Triton X-100 1 %, ET50 = 8.7 ± 0.3 h), that were all within the acceptance range. Technical proficiency was assessed testing the ten proficiency substances listed in Annex 3 of the OECD TG 439, as previously reported.² In addition, unspecific interaction of rGOs with the MTT readout was preliminary evaluated on "killed" RhE, obtained by freezing treatment at - 80°C for 48 h and none of the materials significantly increased MTT conversion, suggesting no unspecific interactions for rGOs.

The assessment of irritation potential of rGOs on SkinEthicTM RhE model was performed following the skin Irritation Test^{42bis}, in compliance with the OECD TG 439, as previously reported for other graphene-related materials (Fusco et al., 2020). Briefly, after being wetted with 10 μ L of distilled water, RhE tissues (dimensions of 0.5 cm², at day 17) were topically exposed to 16 mg of each rGO (concentration of 32 mg cm⁻²) in triplicate for 42 min at room temperature (RT). As negative and positive controls, RhE tissues were exposed to phosphate buffered saline (PBS) or 5% w/v sodium dodecyl sulphate (SDS), respectively. After exposure, RhE tissues were washed 25 times with 1 mL PBS and transferred in a 6-well plate with 2 mL growth medium for 42 h at 37 °C and 5% CO₂. Tissue were then transferred in a 24-well plate containing 300 μ L of MTT solution (1 mg mL⁻¹) for 3 h at 37 °C and 5% CO₂ and the resulting formazan salts were extracted with isopropanol (1.5 mL per well, for 2 h at RT) and measured at 570 nm using the FLUOstar® Omega microplate reader (BMG LABTECH, Ortenberg, Germany). Tissue viability is reported as % of negative controls and are the mean ± standard error (SD) of three independent experiments.

Interleukin-1α quantitation

After 42 minutes of exposure to rGO or positive control followed by 42 hours of post-incubation time, culture media were collected and stored at -80 °C. Interleukin (IL)-1α was quantified

using a specific sandwich ELISA kit from Diaclone (Tema Ricerca, Milan, Italy) following the producer's instructions. Results are expressed as pg/mL of IL-1 α released by the tissues in the growth medium and are the mean \pm SD of three independent experiments.

Statistical analysis

For skin irritation (OECD TG 439), the results are expressed as % of tissue viability with respect to negative controls and are the mean \pm SD of three independent experiments. As a threshold given by OECD TG 439, viability \leq 50 % defines an irritant material.

Statistical analysis was performed by a one-way ANOVA followed by Bonferroni's post-test (GraphPad Prism version 8.00) and statistical significance was considered for p < 0.05.

Table S2. State of the art of the conditions to obtain chemical reduced graphene oxide, their structural characteristics and their electrical performances.

Reducing agent	Concentration Reducing agent [g/L]	Concentration GO [g/L]	pH adjusting reagent	Reaction time [h]	Reaction temperature [°C]	C/O ratio XPS	Electrical conductivity [S/m]	Surface area BET [m²/g]	Capacitance [F/g]	Ref.
	ę	1	5 wt%	2	07	4.64	27	442.53 Pore size: 3.20 nm	86 F/g at 0.5 A/g, 1M H ₂ SO ₄ , two- electrode configuration	This
	0	I	K ₂ CO ₃	12	33	4.76	41	555.63 Pore size: 9.60 nm	211 F/g at 0.5 A/g, 1M H ₂ SO ₄ , two- electrode configuration	work
NaBH4	7	1	6 M KOH/ ammonia solution	8	95	10.00	48	-	126.4 F/g at 1 A/g 6M KOH three- electrode configuration	3
	0.57	0.5	-	4	4 RT	1.65			1.1 F/g at 0.05 A/g PVA/H ₃ PO ₄ three- electrode configuration	
	1.89					1.65		-	1.5 F/g at 0.05 A/g PVA/H ₃ PO ₄ three- electrode configuration	4
	3.78					1.59			5.9 F/g at 0.05 A/g PVA/H ₃ PO ₄ three-	

									electrode	
									configuration	
									30.1 F/g at	
									0.05 A/g	
	1.80				105	4.04			PVA/H ₃ PO ₄	
	1.09				105	4.04			three-	
									electrode	
									configuration	
								290.35	183 F/g at	
								Pore	1 A/g	
	10	1	5 M KOH	24	180	_		volume	$1 \text{ M H}_2 \text{SO}_4$	5
	10		(5mL)	21	100			$0.4 \text{ cm}^{3/g}$	three-	
								Pore size	electrode	
								4.82 nm	configuration	
									120 F/g at	
	NDUCCO							164.13	l A/g	
	NaBH ₄ to GO	-	-	8	98	-		Pore size	IM E.NDE /DC	6
	(10:1)(m/m)							7.18 nm	Et ₄ NBF ₄ /PC	
									two-electrode	
									configuration	
								202.84	$55 \Gamma/g \text{ at } 0.5$	
				2			202	292.04 Doro sizo:	A/g, INI	
				2				$\begin{array}{c} 1 \text{ or } e \text{ size.} \\ 6 30 \text{ nm} \end{array}$	alactrode	
								0.57 IIII	configuration	This
	8	1	25 wt% NH ₃		95				121 F/g at 0.5	work
								394.90	A/g. 1M	WOIR
				12			1851	Pore size:	H ₂ SO ₄ , two-	
							1001	13.70 nm	electrode	
Ascorbic acid (AA)									configuration	
	0.1	0.1	-	48	RT	-	800	-	-	7
								510	128 F/g at	
								J1Z Darra	50mA/g	
	12	4	-	16	40	-	100	Pore	6 M KOH	8
								$2.48 \text{ cm}^{3/\alpha}$	two-electrode	
								2.48 cm²/g	configuration	
			25%			0.08				
	0.35	0.1	ammonia	0.25	95	(0/C)	7700	-	-	9
			solution (2µL							

			per mL)							
	1	0.1	25% ammonia solution (20μL per mL)	2	95	5.15	980	-	-	10
	AA to GO (1:5) (<i>m/m</i>)	-	-	4	90	-	220	81 Pore volume 1.22 cm ³ /g	79 F/g at 1 A/g 2 M KOH three- electrode configuration	11
	3	0.1	-	48	RT	3.5	_	-	63.5 F/g at 100 mV/s 1 M H ₂ SO ₄ three- electrode configuration	12
	AA to GO (10:1) (<i>m/m</i>)	-	-	24	80	-	-	240.97 Pore size 5.17 nm	133 F/g at 1 A/g 1M Et ₄ NBF ₄ /PC two-electrode configuration	6
AA/NaHSO3	AA to NaHSO ₃ (1:1) Reductant to GO (1:5) (<i>m/m</i>)	-	-	4	90	-	360	135 Pore volume 2.9 cm ³ /g	165 F/g at 1 A/g 2 M KOH three- electrode configuration	11
Hydrazine hydrate	10	1	-	2	95		1857	96.41 Pore size: 5.20 nm	57 F/g at 0.5 A/g, 1M H ₂ SO ₄ , two- electrode configuration	This
				12			3848	124.92 Pore size: 6.4 nm	92 F/g at 0.5 A/g, 1M H ₂ SO ₄ , two- electrode	WOLK

									configuration			
									205 F/g at			
	5mI							320	100 mA/g			
	(80 wt %)	100mg	-	72	RT	-	-	520	30 wt % KOH	13		
	(00 wt /0)								two-electrode			
									configuration			
									84.7 F/g at			
									1 A/g			
	1:5,	2	-	24	95	14.11	1980	-	$2 \text{ M} \text{H}_2 \text{SO}_4$	14		
	GO/hyrdrazine	-				1	1900		three-			
									electrode			
									configuration			
									152.5 F/g at			
									l A/g			
	10	1	ammonia	8	95	11.74	76	-	6M KOH	3		
			solution						three-			
									electrode			
									configuration			
								140.01	3/F/g at 0.5			
				2			3360	140.91 Doro sizo:	A/g, IW			
				2			5509	1 ore size.	alactrode			
								1.4 1111	configuration	This		
	7.5	1	25 wt% NH ₃		95				106 F/g at 0 5	work		
Sodium dithionite								278 34	$\Delta/\sigma 1M$	WUIK		
				12			4324	Pore size	H ₂ SO ₄ two-			
				12				7.30 nm	electrode			
									configuration			
	12.5	GO film	NaOH	0.25	60	-	1377	-	-	15		
	7.5	1	25 wt% NH ₃	12	90	6.6	-	-	-	16		
			ammonia	0		1.9:1	-					
Hudrovylamine			aqueous	0.5		6.1:1	-					
(NH OH)	0.5	0.25	solution (30%		90			-	-	17		
(1112011)			in volume)	1		9.7:1	1122					
			200µL									
Liquid								466	200 F/g at			
borane-THF adduct	1.5mL	3	-	96	100	7.8	50	Pore size	0.1A/g	18		
Sodium dithionite Hydroxylamine (NH ₂ OH) Liquid borane-THF adduct	borane-THF adduct		1.51112							2.13nm	6M KOH	

									two-electrode configuration 193 F/g at	-
									0.1 A/g 6M KOH	
									three-	
									electrode	
									41 F/g at	
Hibiscus sabdariffa L.	200mL of extract	0.4	0.01M H ₂ SO ₄	1	At refluxed [100]	3.0	-	-	100 mV/s 133.07 at 5 mV/s	19
aqueous extract									two-electrode system	
Pyrogallol	lmM	0.1	25% ammonia solution (2μL per mL)	1	95	0.18 (O/C)	488	-	-	9
HBr	3mL (40%)	0.1	-	24	110	3.9	0.023	-	129 F/g at 10 mV/s 1 M H ₂ SO ₄ two-electrode 348 F/g at 0.2A/g 1 M H ₂ SO ₄ two-electrode 158 F/g at 0.2A/g 1 M BMIPF ₆ two-electrode 171 F/g at	20
									10 mV/s 1 M H ₂ SO ₄ three- electrode configuration	
HI	HI vapours	Spin coated	-	0.08	90	-	831.35	-	-	21

		layer								
	HI (45%)		-	2		7.1	-		180 F/g at 10 mV/s 1 M H ₂ SO ₄ three- electrode configuration	22
L-serine	3	1	NaOH/HCl diluted solutions	10	90	7.9	-	-	-	23
L-cysteine	10	0.5	-	72	RT	-	0.124	-	-	24
D-glucose	3	0.1	25% ammonia solution	2	95	2.89	315	-	-	10
			ammonia	24	RT	3.89	0.96			
Gallic acid	40	4	aqueous solution 1.2mL	6	95	5.28	36	-	_ 2	25
KOH/ hydrazine hydrate	1:5 (<i>m/m</i>) GO/hyrdrazine	2	-	24	95	10.13	431	-	253 F/g at 0.2 A/g 2 M H ₂ SO ₄ three- electrode configuration	14
Thiourea	28	5	NaOH	1	90	14.5	-	_	_	26
dioxide				2		16.0				
Sn - powder	5	1	HCl (35%) 20mL	3	40	6.1	8.650	-	152 F/g at 1.5 A/g 1 M H ₂ SO ₄ three- electrode configuration	27
Zn - powder	Zn powder scattered 74µL	1	25% ammonia solution	0.16	RT	8.05	2.160	-	116 F/g at 0.05 A/g 6 M KOH three- electrode configuration	28

Al - powder	5	1	0.5 M HCl 5mL	0.5	RT	18.6	2.100	365	-	29
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Section B. Physical characterization



Fourier-transform infrared (FTIR) spectroscopy

Figure S1. FTIR spectra of chemically reduced GO with different reducing agents at a) 2 hours and b) 12 hours reaction time.

Elemental analysis (EA)

Sample	%C	%O	%N	%S	%Н	C/O
GO	46.10	46.60	0.03	2.00	5.27	0.99
rGO(NaBH ₄)_2h	65.00	31.94	0.17	1.17	1.73	2.04
rGO(NaBH4)_12h	66.72	30.29	0.58	1.11	1.30	2.20
rGO(AA)_2h	75.51	20.59	1.99	0.88	1.03	3.67
rGO(AA)_12h	70.74	26.32	0.97	0.92	1.05	2.69
$rGO(N_2H_4)_2h$	80.28	14.62	3.35	1.01	0.74	5.49
$rGO(N_2H_4)_{12h}$	83.50	11.60	3.63	0.74	0.54	7.20
$rGO(Na_2S_2O_4)_2h$	81.47	14.89	0.72	2.16	0.77	5.47
$rGO(Na_2S_2O_4)_12h$	84.78	12.07	0.41	2.09	0.65	7.02

Table S3. Elemental analysis of chemically reduced GO samples.

X-ray Photoelectron Spectroscopy (XPS)



Figure S2. Survey spectra of GO.



Figure S3. Survey spectra of chemically reduced GO with different reducing agents and different reaction times.

Sample	%C	%O	%N	%Na	C/O
GO	46.10	53.87	0.03	-	0.86
rGO(NaBH ₄)_2h	81.12	17.50	-	1.37	4.64
rGO(NaBH ₄)_12h	82.10	17.25	-	0.65	4.76
rGO(AA)_2h	87.37	12.63	-	-	6.92
rGO(AA)_12h	87.80	12.20	-	-	7.20
$rGO(N_2H_4)_2h$	89.79	8.45	1.76	-	10.63
$rGO(N_2H_4)_12h$	88.50	8.60	2.90	-	10.29
$rGO(Na_2S_2O_4)_2h$	91.39	8.61	-	-	10.62
$rGO(Na_2S_2O_4)_{12h}$	91.81	8.19	-	-	11.21

Table S4. Elemental analysis of chemically reduced GO samples from XPS survey.



Figure S4. High-resolution XPS spectra of C1s for the CrGO with different reducing agents and different reaction times.



Figure S5. High-resolution XPS spectra of O1s for the CrGO with different reducing agents and different reaction times.



Figure S6. XPS analysis of 1Ns spectra of CrGO with hydrazine at a) 2 and b) 12 hours of reduction.



Figure S7. a-b) relative contribution of a) C1s peak and b) O1s peak components estimated by dividing the area under each component by whole a) C1s peak area and b) O1s peak area as a function of the reducing agents and reaction time.

Solid-state MAS NMR



Figure S8. Solid-state MAS-NMR C1s spectra of chemically reduced GO.



Figure S9. Relative contribution of NMR spectra components as a function of the reducing agents and reaction time estimated by dividing the area under each component by the whole peak area.



Figure S10. Comparison of the relative contribution of a) C1S XPS and b) NMR spectra components as a function of the reducing agents and reaction time estimated by dividing the area under each component by the whole peak area.

Raman spectroscopy



Figure S11. Overlapped Raman spectra of GO and CrGO with different reducing agents at a) 2 and b) 12 hours of reaction time.



Figure S12. Fitted Raman spectra of CrGO with different reducing agents and different reaction times.



Figure S13. Ratio of the band intensities a) I_D/I_G b) $I_{D''}/I_G$ c) $I_{D''}/I_G$ d) I_{D*}/I_G of CrGO with different reducing agents and different reaction times.



Figure S14. a) Average defect distance and b) defect density of CrGO with different reducing agents and different reaction times.

Powder X-Ray Diffraction (PXRD)

Calculation of the XRD parameters

From the XRD diffractograms the peak position has been calculated using the Bragg's law:

$$d_{(hkl)} = \frac{\lambda}{2\sin\theta} \tag{8}$$

Where $d_{(hkl)}$ is the calculated inter planar distance (Å), λ is the wavelength of the XRD source (Å), θ is the scattering angle (rad). The crystallite dimension has been derived from the Scherrer formula:

$$L_{C} = \frac{K\lambda}{\beta_{a}\cos\theta_{a}} \tag{9}$$

$$L_a = \frac{1.84 \,\lambda}{\beta_b \cos \theta_b} \tag{10}$$

Where Lc is the crystallite thickness (Å), La is the crystallite size (Å), K is the shape factor equal to 0.89,³⁰ β is the FWHM of the (100) and (002) peaks and θ_a and θ_b are the corresponding scattering angles

Table S5. The XRD peak position, d-spacing, crystallite size (L_a) , crystalline thickness (L_c) and average graphene layer number (n_c) calculated for the (002) and (100) planes for all measured samples.

C1	Dentert	Reaction	(0 0 2)	(1 0 0)	d-spacing	7 5 8 3	7 5 8 3	Number
Sample	Reactant	time [h]	position [°]	position [°]	[Å]	$L_{a}[A]$	$L_{\rm c}$ [A]	of layers n_c
GO	-	-	10.05	-	8.79±0.01	226.59±2.68	97.32±3.05	11.07
rGO(NaBH ₄)_2h	NaBH.	2	24.02	42.94	3.73±0.01	130.19±2.91	17.53±0.92	4.74
rGO(NaBH ₄)_12h		12	23.82	943.08	3.70±0.01	117.93±1.59	14.75±0.49	3.95
rGO(AA)_2h	ΔΔ	2	23.55	43.01	3.77±0.01	104.49±1.88	13.81±0.67	3.66
rGO(AA)_12h		12	24.24	42.85	3.67±0.01	92.28±1.46	15.24±0.70	4.16
rGO(N ₂ H ₄)_2h	N ₂ H4	2	23.08	42.97	3.85±0.01	93.30±2.99	12.52±0.77	3.25
rGO(N ₂ H ₄)_12h	142114	12	23.34	42.74	3.81±0.01	100.77±2.33	14.19±0.71	3.73
rGO(Na ₂ S ₂ O ₄)_2h	Na ₂ S ₂ O ₄	2	23.51	42.79	3.78±0.01	107.64±3.32	18.23±0.79	4.82
$rGO(Na_2S_2O_4)_12h$	1,02,02,04	12	23.77	42.85	3.74±0.01	99.66±1.71	17.95±0.69	4.80

Scanning electron microscopy (SEM)



Figure S15. SEM image of GO.



Figure S16. SEM images and CrGO with different reducing agents and different reaction times.





Figure S17. TGA diagram for the CrGO with different reducing agents at a) 2 and b) 12 hours of reaction time.

BET characterization



Figure S18. BET surface area for GO.



Figure S19. BET surface area for CrGO with different reducing agents and different reaction times.



Figure S20. Pore size distribution of GO.



Figure S21. Pore size distribution of CrGO with different reducing agents and different reaction times.



Figure S22. a) Specific surface area and b) average pore diameter obtained from BET isotherms.



Figure S23. Film conductivity of CrGO with different reducing agents and different reaction times. Inset, lateral and frontal side of a representative pellet.



Figure S24. Optical images of the films of GO and CrGO with different reducing agents.



Figure S25. a, c) Resistance of the CrGO film obtained with a) $Na_2S_2O_4$ and c) AA, as a function of time during the application of 2000 bending cycles, b, d) magnification of the film resistance of CrGO obtained with b) $Na_2S_2O_4$ and d) AA, as a function of time.





Figure S26. CV curves of CrGO with different reducing agents at different reaction times at different scan rates. The units of scan rate are mV/s.



Figure S27. GCD curves of CrGO with different reducing agents and different reaction times at different scan rates.



Figure S28. Comparison of specific capacitances versus current densities of CrGO with different reducing agents at a) 2 and b) 12 hours of reaction time.



Figure S29. Specific capacitances at 0.5 A/g of CrGO with different reducing agents and reactions times compared with their corresponding (a) surface area, (b) pore size, (c) electrical conductivity (d) ionic conductivity and (e) oxygen content. Ionic conductivities were calculated by EIS.



Figure S30. The equivalent electric circuit models used for fitting the Nyquist plots. Ri: the bulk resistance; Rct: charge transfer resistance; C_1 : capacitance element; CPE_{EDL} : constant phase element representing the electrical double layer capacitance (EDLC).

Sample	$\operatorname{Ri}(\Omega)$	$R_{CT}(\Omega)$	σ (S/m)
GO	0.95 ± 0.04	12.33 ± 0.61	0.83
rGO(NaBH ₄)_2h	1.66 ± 0.02	1.45 ± 0.03	0.48
rGO(NaBH ₄)_12h	0.76 ± 0.01	2.21 ± 0.03	1.04
rGO(AA)_2h	13.31 ± 0.02	1.71 ± 0.03	0.06
rGO(AA)_12h	2.43 ± 0.02	2.09 ± 0.03	0.32
$rGO(N_2H_4)_2h$	5.18 ± 0.02	0.63 ± 0.02	0.15
$rGO(N_2H_4)_{12h}$	1.79 ± 0.02	3.99 ± 0.07	0.44
$rGO(Na_2S_2O_4)_2h$	10.55 ± 0.03	3.20 ± 0.04	0.07
$rGO(Na_2S_2O_4)_12h$	1.56 ± 0.01	0.70 ± 0.01	0.51

Table S6. Fitting parameters obtained from the Nyquist plots.



Figure S31. a), c) Cycling stability and b), d) coulombic efficiency of CrGO at the current density of 1 A/g.



Figure S32. Ragone plot for CrGO using different reducing agents at a) 2 and b) 12 hours of reaction time.



Figure S33. Optical images of the water sessile drop at different times on the CrGO-based films with the fitted contact angle represented.

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